


SANYO Semiconductors

DATA SHEET

TND517VS — ExPD(Excellent Power Device) Single-phase High Side Drive Application

Features

- Single-phase high side driver.
- Monolithic structure.
- Allows simplified configuration of driver circuit.
- Withstand voltage of 600V is assured.
- Fully compatible input to LSTTL/CMOS.
- High-speed switching.
- Output current: 170mA Source, 340mA Sink.

Specifications

Absolute Maximum Ratings at Ta=25°C (All voltage parameters are absolute voltage referenced to GND)

Parameter	Symbol	Conditions	Ratings	Unit
High Side Floating Supply Voltage	V _H		-0.3 to 625	V
High Side Floating Supply Offset Voltage	V _S		V _H -25 to V _H +0.3	V
High Side Output Voltage	V _{HOUT}		V _S -0.3 to V _H +0.3	V
Logic Supply Voltage	V _{DD}		-0.3 to 25	V
Logic Input Voltage	V _{HIN}		-0.3 to V _{DD} +0.3	V
Allowable Power Dissipation	P _D		0.2	W
Junction Temperature	T _j		-55 to +150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Recommend Operating Conditions at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
High Side Floating Supply Voltage	V _H		V _S +10 to V _S +20	V
High Side Floating Supply Offset Voltage	V _S		0 to 600	V
High Side Output Voltage	V _{HOUT}		V _S to V _H	V
Logic Supply Voltage	V _{DD}		+10 to +20	V
Logic Input Voltage	V _{HIN}		0 to V _{DD}	V
Ambient Temperature	T _{opr}		-40 to +125	°C

■ Any and all SANYO Semiconductor Co.,Ltd. products described or contained herein are, with regard to "standard application", intended for the use as general electronics equipment (home appliances, AV equipment, communication device, office equipment, industrial equipment etc.). The products mentioned herein shall not be intended for use for any "special application" (medical equipment whose purpose is to sustain life, aerospace instrument, nuclear control device, burning appliances, transportation machine, traffic signal system, safety equipment etc.) that shall require extremely high level of reliability and can directly threaten human lives in case of failure or malfunction of the product or may cause harm to human bodies, nor shall they grant any guarantee thereof. If you should intend to use our products for applications outside the standard applications of our customer who is considering such use and/or outside the scope of our intended standard applications, please consult with us prior to the intended use. If there is no consultation or inquiry before the intended use, our customer shall be solely responsible for the use.

■ Specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.

TND517VS

AC Characteristics at Ta=25°C (VDD=VHS=15V, CL=1000pF)

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Turn-ON Delay Time	t _{on}	V _S =0V		125		ns
Turn-OFF Delay Time	t _{off}	V _S =600V		115		ns
Turn-ON Rise Time	t _r			110		ns
Turn-OFF Fall Time	t _f			40		ns

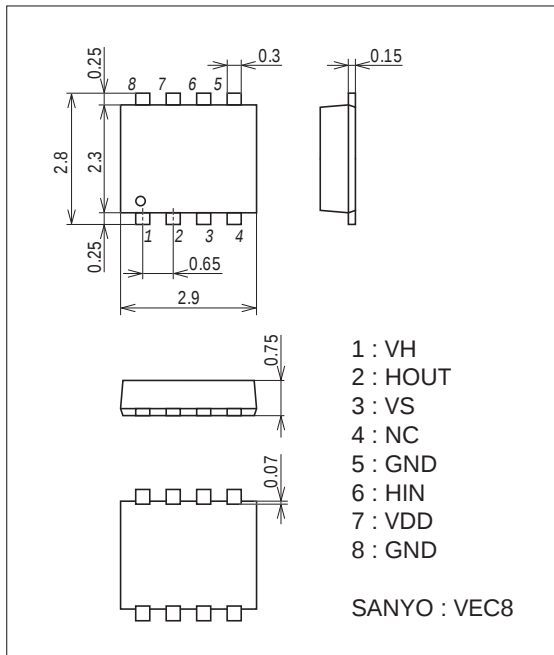
DC Characteristics at Ta=25°C (VDD=VHS=15V)

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Logic "1" Input Voltage	V _{IH}	V _{DD} =10 to 20V	3.0			V
Logic "0" Input Voltage	V _{IL}	V _{DD} =10 to 20V			0.8	V
High-level Output Voltage, VBIAS-V _O	V _{OH}	V _{HIN} =V _{IH} , I _O =0A			0.1	V
Low-level Output Voltage, V _O	V _{OL}	V _{HIN} =V _{IL} , I _O =0A			0.1	V
Offset Supply Leakage Current	I _{LK}	V _H =V _S =600V			10	μA
Quiescent V _H Supply Current	I _{QH}	V _{HIN} =0V or V _{DD}		70	120	μA
Quiescent V _{DD} Supply Current	I _{QDD}	V _{HIN} =0V or V _{DD}		140	230	μA
Logic "1" Input Bias Current	I _{IN} ⁺	V _{HIN} =V _{DD}		20	55	μA
Logic "0" Input Bias Current	I _{IN} ⁻	V _{HIN} =0V			1	μA
V _H Supply Undervoltage Positive Going Threshold	V _{HUV} ⁺		7.6	8.9	9.9	V
V _H Supply Undervoltage Negative Going Threshold	V _{HUV} ⁻		6.7	8.1	9.5	V
V _{DD} Supply Undervoltage Positive Going Threshold	V _{DDUV} ⁺		7.6	8.9	9.9	V
V _{DD} Supply Undervoltage Negative Going Threshold	V _{DDUV} ⁻		6.7	8.1	9.5	V
Output High Short Circuit Pulsed Current	I _O ⁺	V _{HOUT} =0V, V _{HIN} =15V, PW≤10μs	170	200		mA
Output Low Short Circuit Pulsed Current	I _O ⁻	V _{HOUT} =15V, V _{HIN} =0V, PW≤10μs	340	400		mA

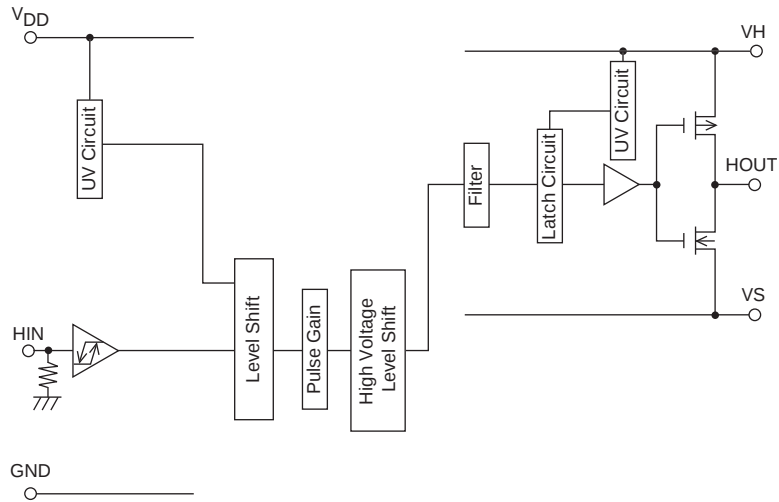
Package Dimensions

unit : mm (typ)

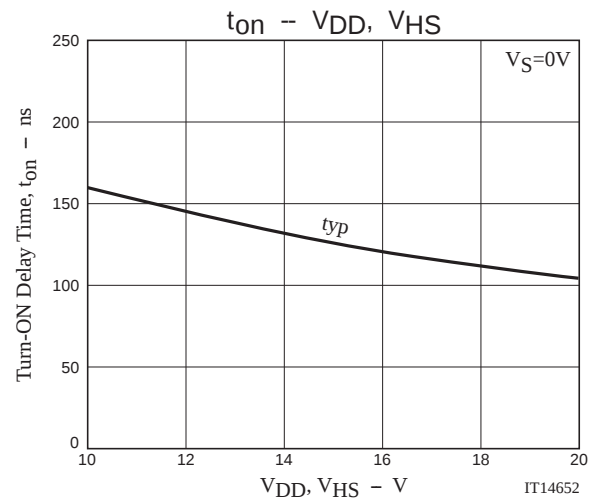
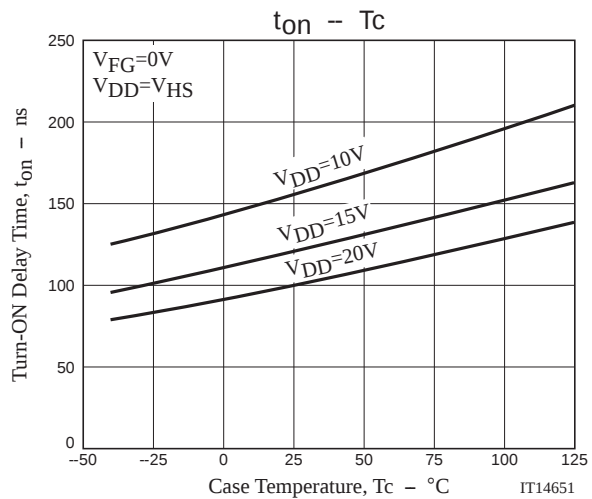
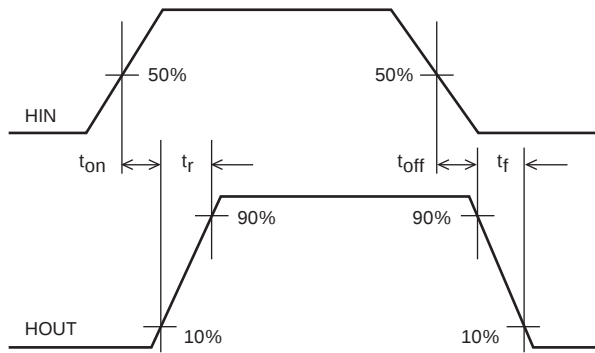
7012-012



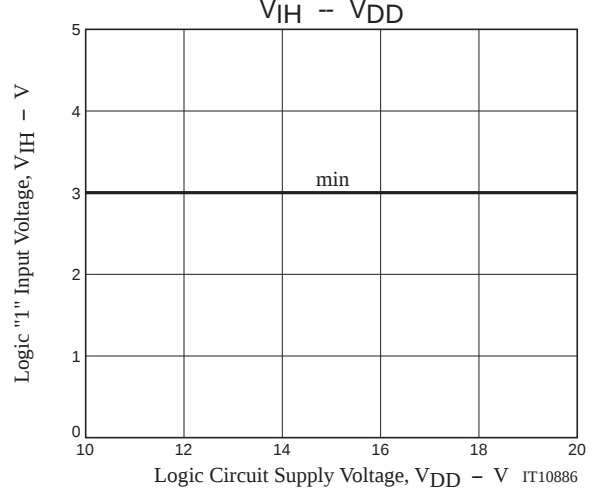
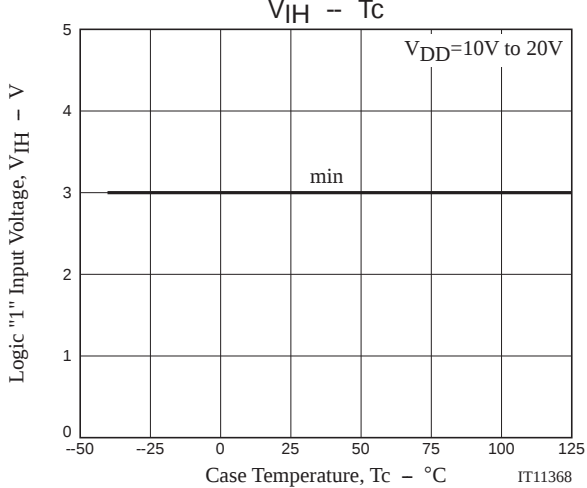
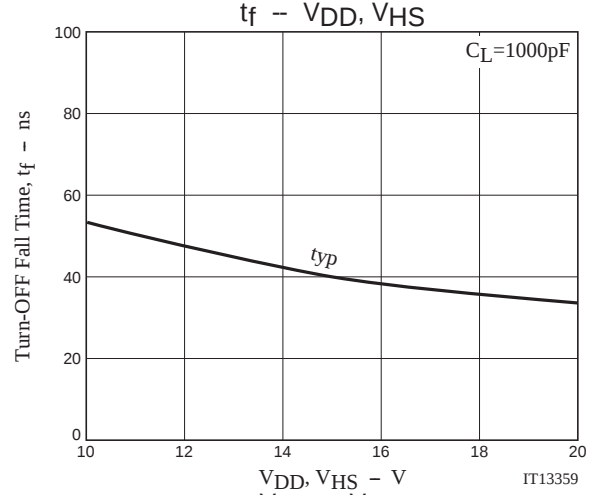
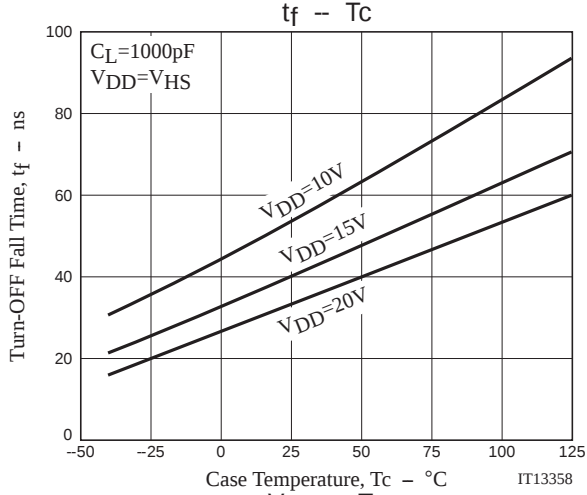
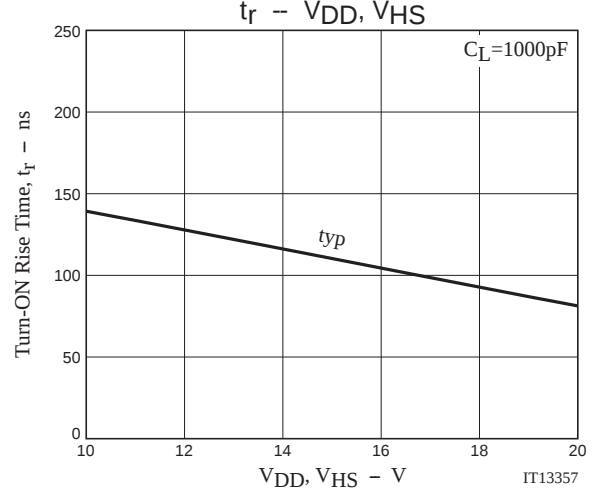
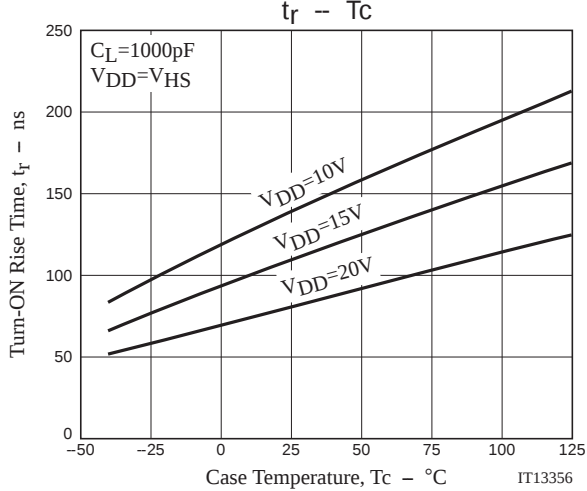
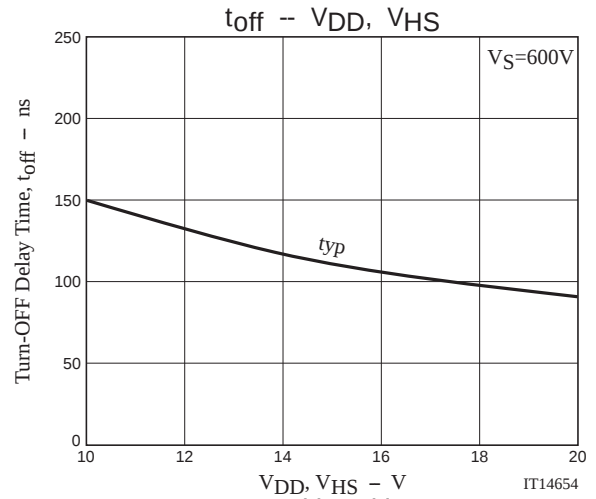
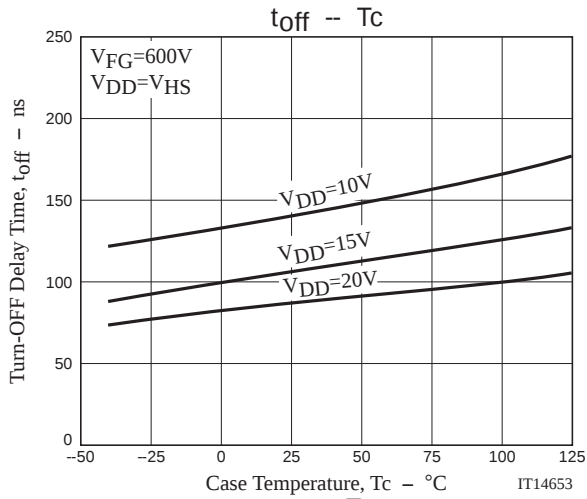
Block Diagram



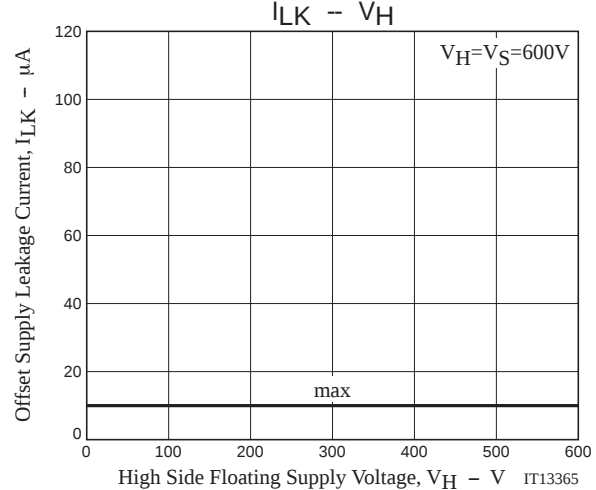
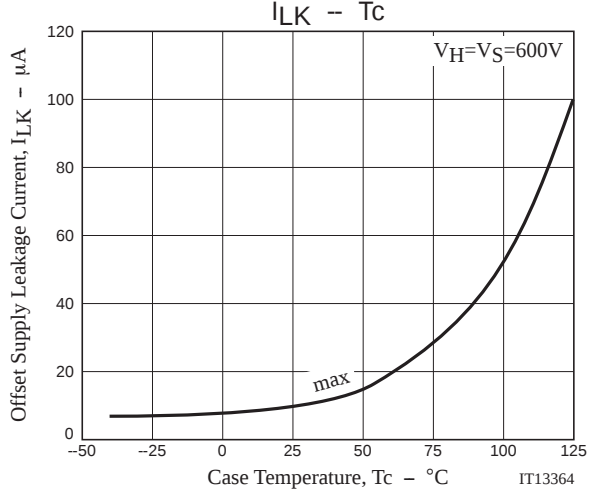
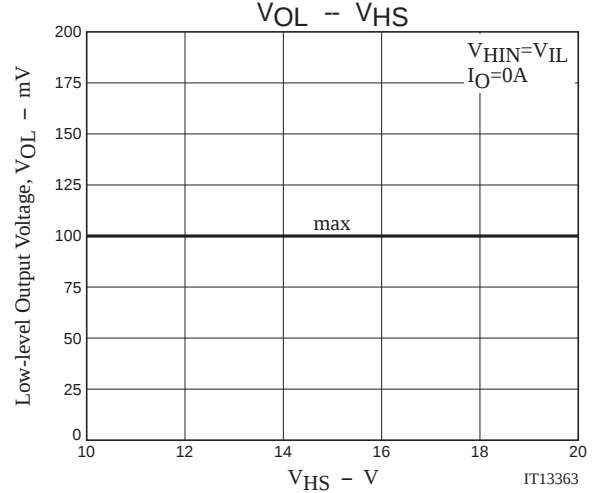
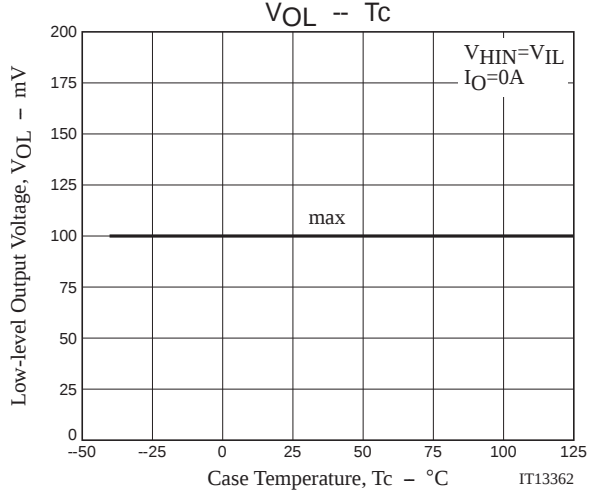
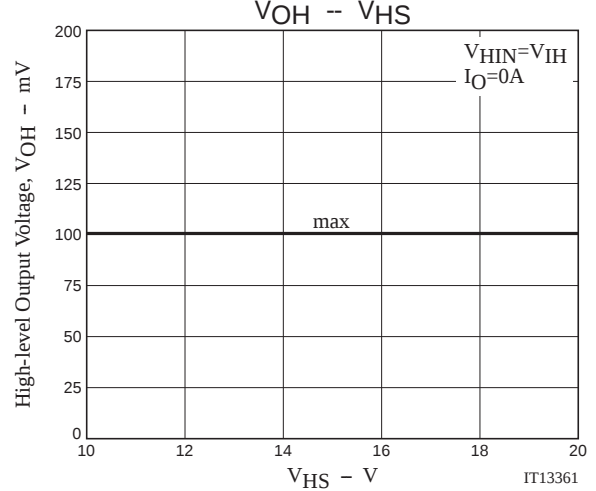
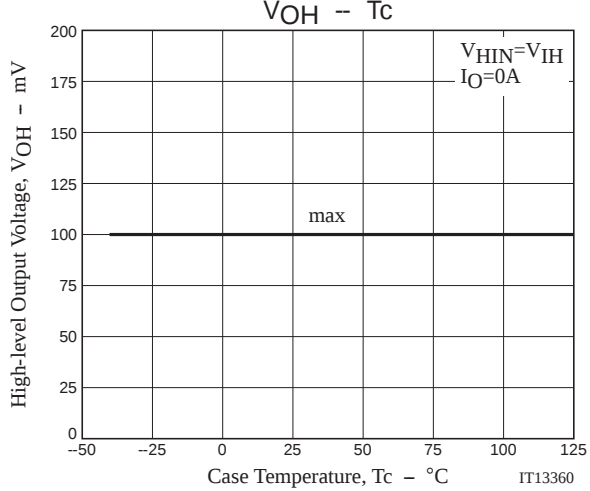
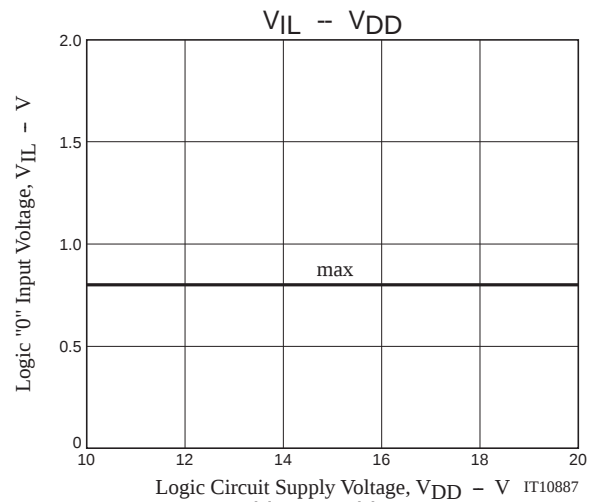
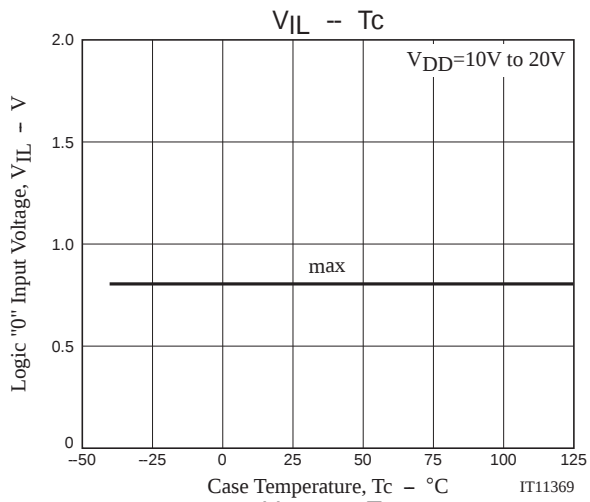
Switching Time Waveform Definition

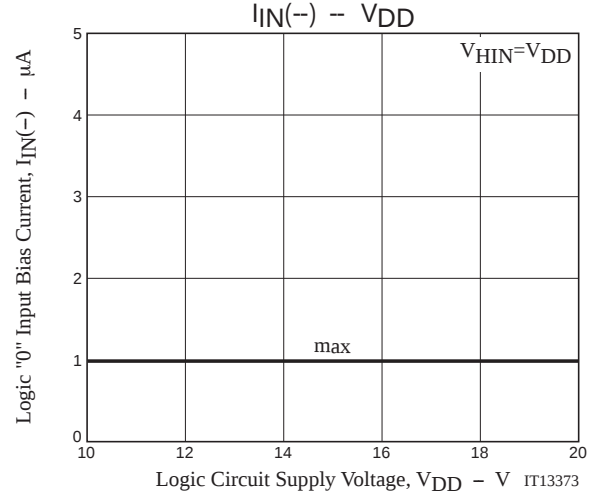
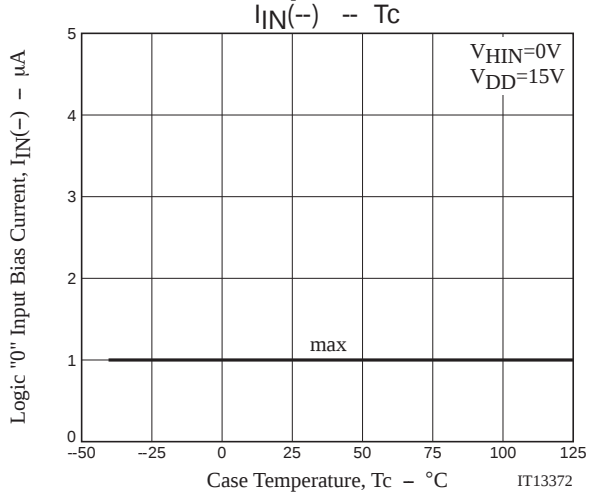
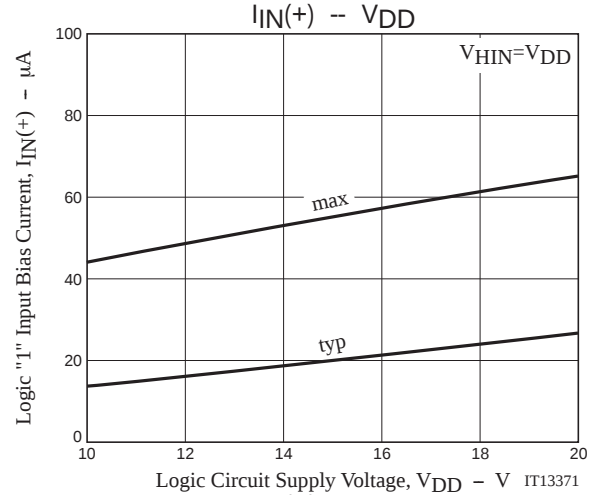
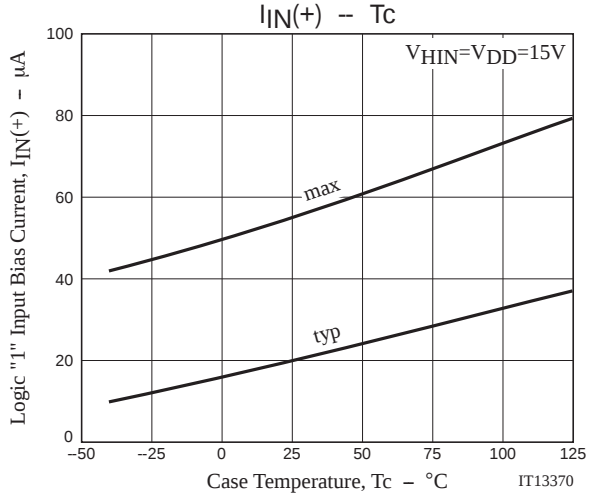
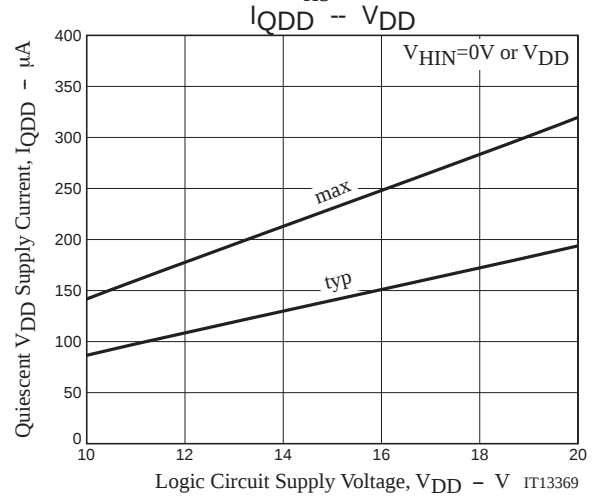
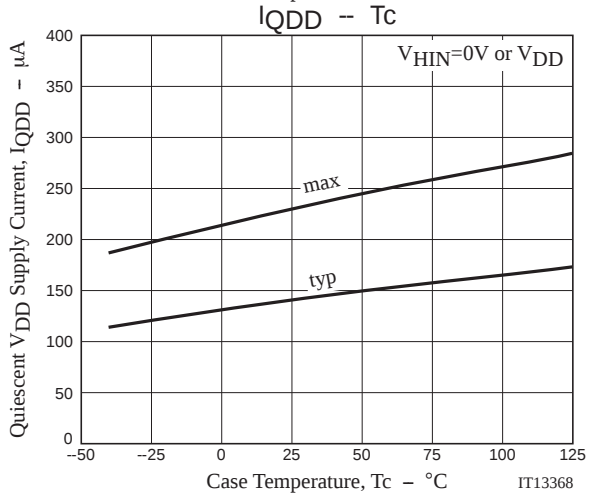
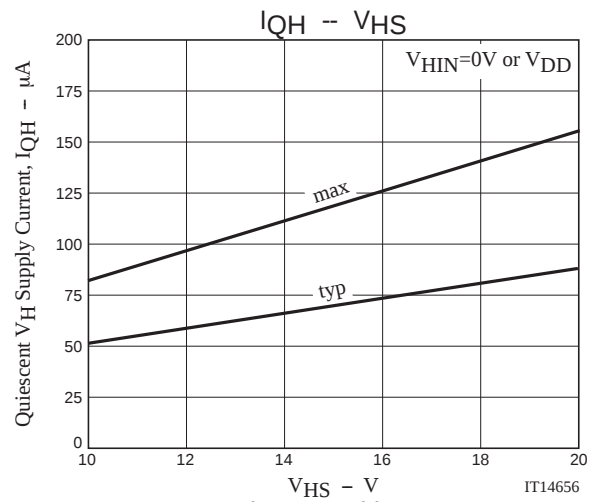
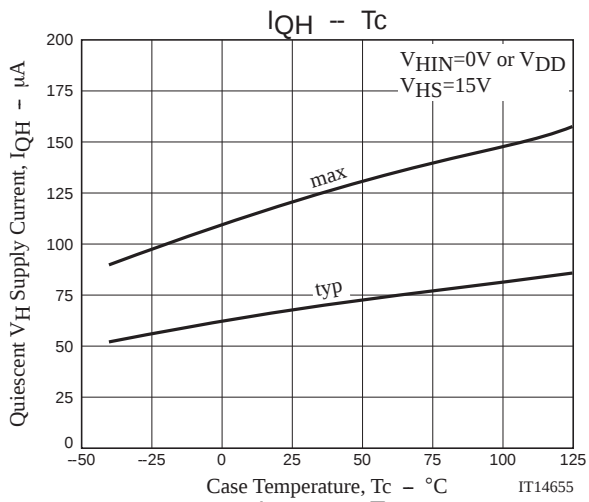


TND517VS

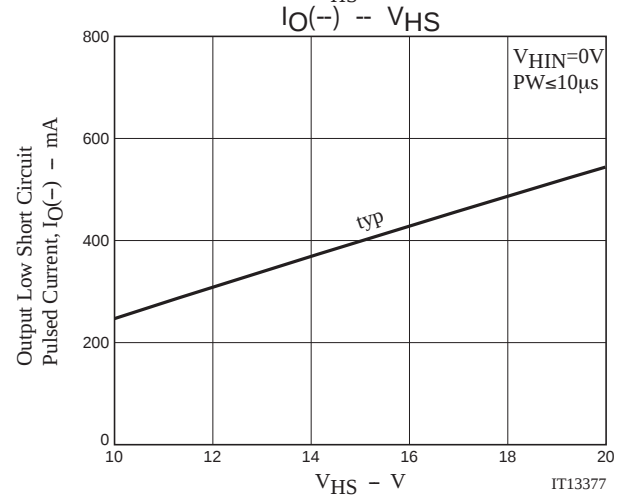
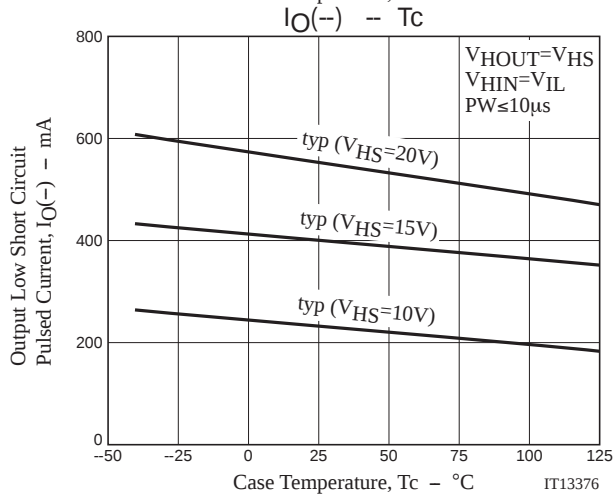
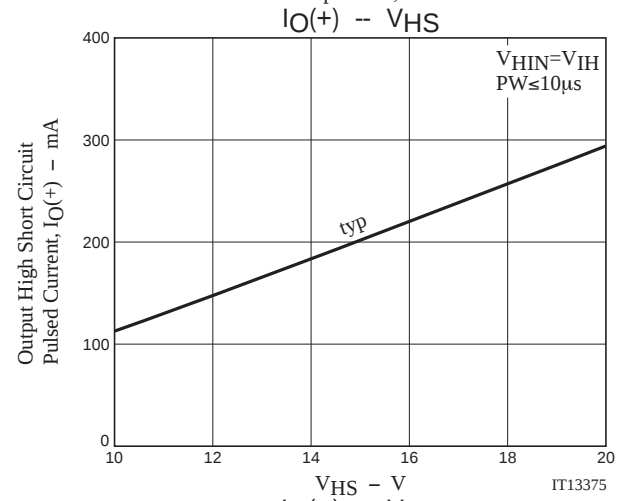
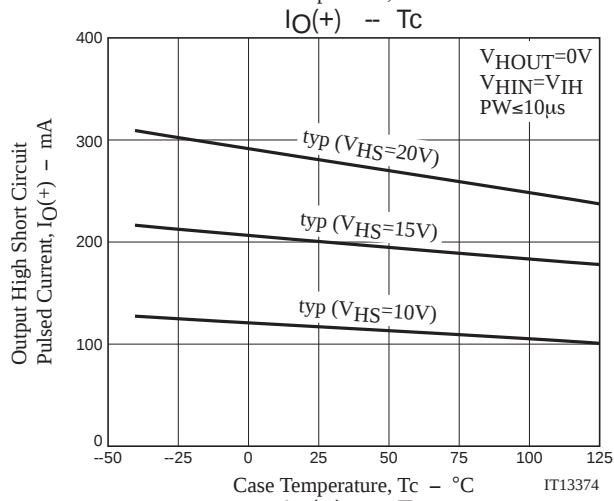
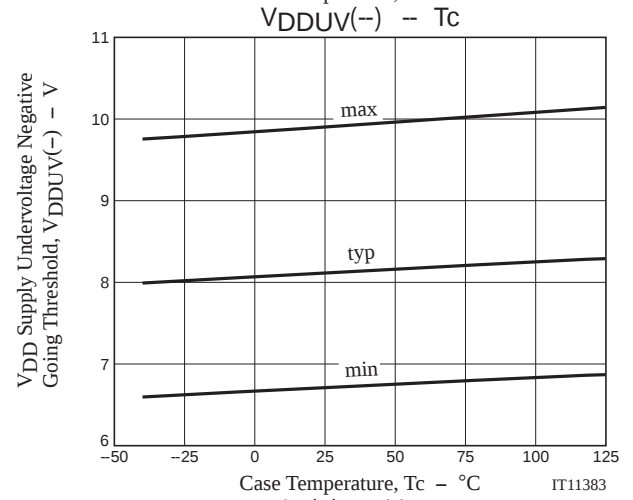
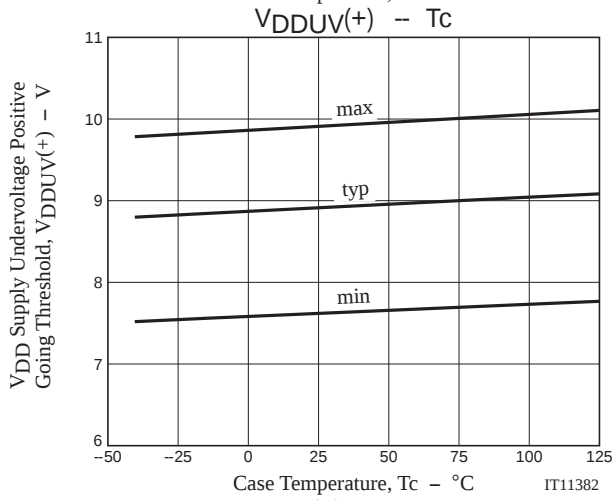
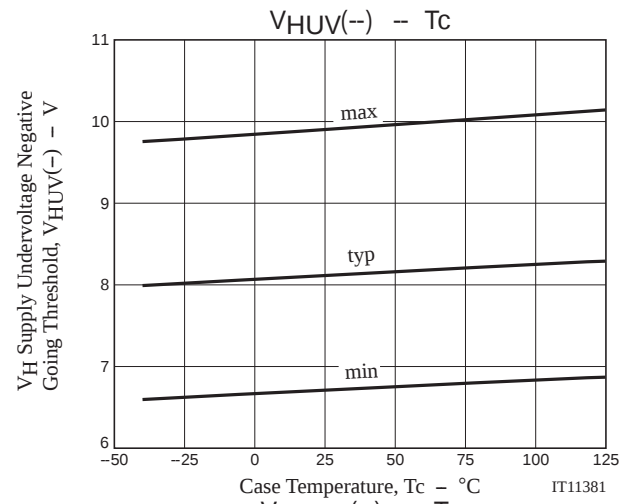
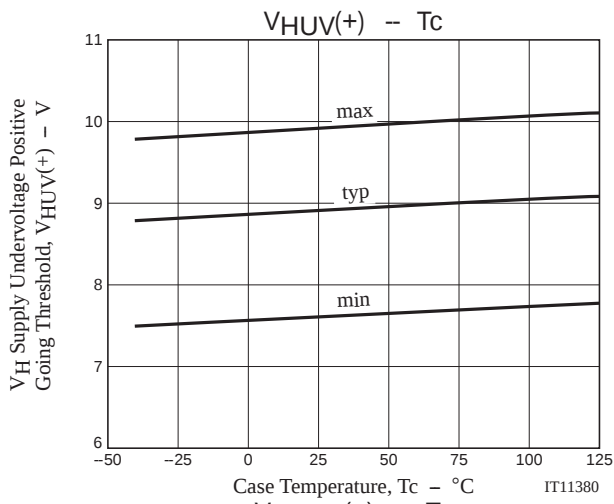


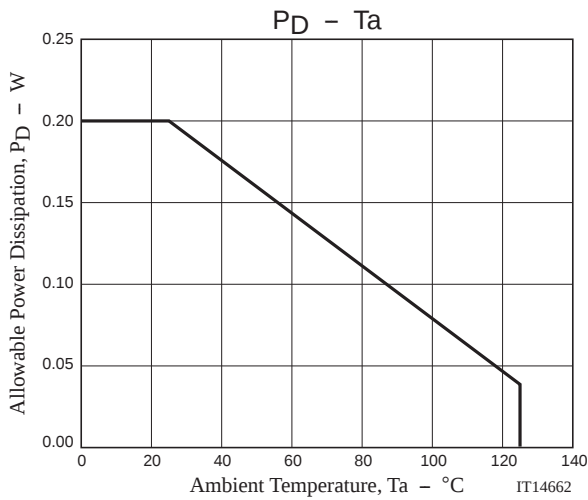
TND517VS





TND517VS





- SANYO Semiconductor Co.,Ltd. assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein.
- SANYO Semiconductor Co.,Ltd. strives to supply high-quality high-reliability products, however, any and all semiconductor products fail or malfunction with some probability. It is possible that these probabilistic failures or malfunction could give rise to accidents or events that could endanger human lives, trouble that could give rise to smoke or fire, or accidents that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO Semiconductor Co.,Ltd. products described or contained herein are controlled under any of applicable local export control laws and regulations, such products may require the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written consent of SANYO Semiconductor Co.,Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO Semiconductor Co.,Ltd. product that you intend to use.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production.
- Upon using the technical information or products described herein, neither warranty nor license shall be granted with regard to intellectual property rights or any other rights of SANYO Semiconductor Co.,Ltd. or any third party. SANYO Semiconductor Co.,Ltd. shall not be liable for any claim or suits with regard to a third party's intellectual property rights which has resulted from the use of the technical information and products mentioned above.

This catalog provides information as of May, 2009. Specifications and information herein are subject to change without notice.